

# isc Silicon NPN Power Transistor

### **DESCRIPTION**

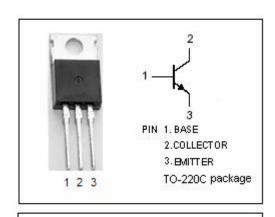
- · Collector-Emitter Breakdown Voltage-
  - : V<sub>(BR)CEO</sub>= 80V(Min)
- · Good Linearity of hFE
- Wide Area of Safe Operation
- Complement to Type 2SB747
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

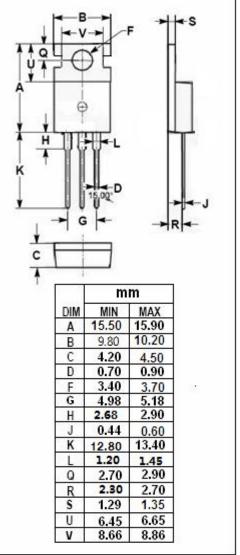
## **APPLICATIONS**

- · High power amplifier applications.
- Suitable for 15~20W home stereo output amplifier and voltage regulator.

# ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>CBO</sub>	Collector-Base Voltage	80	V
Vceo	Collector-Emitter Voltage	80	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
lc	Collector Current-Continuous	5	Α
I <sub>Cp</sub>	Peak Collector Current	8	Α
Pc	Collector Power Dissipation @ Tc=25℃	40	W
TJ	T <sub>J</sub> Junction Temperature		°C
T <sub>stg</sub>	T <sub>stg</sub> Storage Temperature Range		°C







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2SD812

#### **ELECTRICAL CHARACTERISTICS**

T<sub>c</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 3A; I <sub>B</sub> = 0.3A			2.0	V
V <sub>BE(on)</sub>	Base-Emitter On Voltage	I <sub>C</sub> = 3A; V <sub>CE</sub> = 5V			1.8	V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = 80V; I <sub>E</sub> = 0			50	μА
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 3V; I <sub>C</sub> = 0			50	μА
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = 20mA; V <sub>CE</sub> = 5V	20			
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = 1A; V <sub>CE</sub> = 5V	40		200	
h <sub>FE-3</sub>	DC Current Gain	Ic= 3A; VcE= 5V	20			
Сов	Collector Output Capacitance	I <sub>E</sub> = 0; V <sub>CB</sub> = 10V; f= 1MHz		90		pF
f⊤	Current-Gain—Bandwidth Product	I <sub>C</sub> = 0.5A; V <sub>CE</sub> = 5V		15		MHz

## ♦ h<sub>FE-2</sub> Classifications

R	Q	Р
40-80	60-120	100-200

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